Amendments to the Claims:

This listing of claims will replace all prior versions and listings of claims in the application:

Listing of Claims:

Claim 1 (currently amended): A method of forming a heat exchanger, comprising:

- a. forming a manifold layer defining a plurality of apertures; and
- b. forming an interface layer comprising one or more narrowing trenches <u>each</u>
 <u>having a substantially planar floor</u>, each aperture positioned on one side of a
 narrowing trench, whereby a path is defined from a first aperture, through a
 narrowing trench, and to a second aperture.

Claim 2 (original): The method of claim 1, wherein the interface layer comprises a material exhibiting anisotropic etching.

Claim 3 (original): The method of claim 2, wherein the material comprises a <110> oriented silicon substrate.

Claim 4 (original): The method of claim 3, wherein forming an interface layer comprises etching the <110> oriented silicon substrate in an etchant to produce a <111> oriented surface defining a sloping wall of a narrowing trench.

Claim 5 (original): The method of claim 4, wherein the etchant comprises potassium hydroxide (KOH).

Claim 6 (original): The method of claim 4, wherein the etchant comprises tetramethyl ammonium hydroxide (TMAH).

Claim 7 (original): The method of claim 1, wherein the one or more narrowing trenches are formed by a machining process selected from the group consisting of milling, sawing, drilling, stamping, EDM, wire EDM, coining, die casting, and investment casting.

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Claim 8 (original): The method of claim 1, wherein the one or more narrowing trenches are formed by a process selected from the group consisting of electroplating, metal injection molding, LIGA processes, and casting.

Claim 9 (original): The method of claim 1, wherein the manifold layer and the interface layer are formed of a monolithic device.

Claim 10 (original): The method of claim 1, further comprising coupling the manifold layer to the interface layer.

Claim 11 (original): The method of claim 10, wherein coupling the manifold layer to the interface layer comprises adhesively bonding the manifold layer to the interface layer.

Claim 12 (original): The method of claim 10, wherein coupling the manifold layer to the interface layer comprises thermally fusing the manifold layer to the interface layer.

Claim 13 (original): The method of claim 10, wherein coupling the manifold layer to the interface layer comprises anodically bonding the manifold layer to the interface layer.

Claim 14 (original): The method of claim 10, wherein coupling the manifold layer to the interface layer comprises eutectically bonding the manifold layer to the interface layer.

Claim 15 (original): The method of claim 1, wherein the manifold layer comprises a material selected from the group consisting essentially of a plastic, a glass, a metal, and a semiconductor.

Claim 16 (original): The method of claim 1, wherein forming the manifold layer comprises forming a first plurality of interconnected hollow fingers and a second plurality of interconnected hollow fingers, the first plurality of interconnected hollow fingers providing flow paths to the one or more first apertures and the second plurality of interconnected hollow fingers providing flow paths from the one or more second apertures.

Claim 17 (original): The method of claim 16, wherein the first plurality of interconnected hollow fingers and the second plurality of interconnected hollow fingers lie substantially in a single plane.

Claim 18 (original): The method of claim 16, further comprising coupling a pump to the first plurality of interconnected hollow fingers.

Claim 19 (original): The method of claim 1, further comprising coupling a heat-generating source to the interface layer.

Claim 20 (original): The method of claim 19, wherein a bottom surface of the interface layer is integrally formed with the heat-generating source.

Claim 21 (original): The method of claim 19, wherein the heat-generating source comprises a semiconductor microprocessor.

Claim 22 (original): The method of claim 18, further comprising introducing a cooling material to the pump, so that the pump circulates the cooling material along the first plurality of interconnected hollow fingers, to the one or more first apertures, along a plurality of narrowing trenches, to the one or more second apertures, and to the second plurality of interconnected hollow fingers, thereby cooling the heat-generating source.

Claim 23 (original): The method of claim 22, wherein the cooling material comprises a liquid.

Claim 24 (original): The method of claim 23, wherein the liquid comprises water.

Claim 25 (original): The method of claim 22, wherein the cooling material comprises a liquid/vapor mixture.

Claim 26 (original): The method of claim 1, wherein each aperture lies substantially in a single plane, parallel to a lower surface of the interface layer.

Claim 27 (original): The method of claim 1, wherein the manifold layer comprises a surface that extends into each narrowing trench and substantially conforms to a contour of each narrowing trench.

Claim 28 (original): The method of claim 1, wherein a narrowing trench has a depth:width aspect ratio of at least approximately 10:1.

Claim 29 (original): The method of claim 1, further comprising coupling an intermediate layer between the manifold layer and the interface layer, the intermediate layer comprising a plurality of openings positioned over the plurality of apertures, thereby controlling the flow of a cooling material to the paths.

Claim 30 (currently amended): A heat exchanger comprising:

- a. a manifold layer defining a plurality of apertures; and
- b. an interface layer comprising a plurality of narrowing trenches, each aperture positioned on one side of a narrowing trench <u>having a substantially planar floor</u>, whereby a path is defined from a first aperture, through a narrowing trench, and to a second aperture.

Claim 31 (original): The heat exchanger of claim 30, wherein the interface layer comprises a material exhibiting anisotropic etching.

Claim 32 (original): The heat exchanger of claim 31, wherein the material exhibiting anisotropic etching comprises a <110> oriented silicon substrate.

Claim 33 (original): The heat exchanger of claim 32, wherein the interface layer is formed by etching the <110> oriented silicon substrate in an etchant to produce a <111> oriented surface defining a sloping wall of a narrowing trench.

Claim 34 (original): The heat exchanger of claim 33, wherein the etchant comprises potassium hydroxide (KOH).

Claim 35 (original): The heat exchanger of claim 33, wherein the etchant comprises tetramethyl ammonium hydroxide (TMAH).

Claim 36 (original): The heat exchanger of claim 30, wherein the narrowing trenches are formed by a machining process selected from the group consisting of milling, sawing, drilling, stamping, EDM, wire EDM, coining, die casting, and investment casting.

Claim 37 (original): The heat exchanger of claim 30, wherein the narrowing trenches are formed by a process selected from the group consisting of electroplating, metal injection molding, LIGA processes, and casting.

Claim 38 (original): The heat exchanger of claim 30, wherein the manifold layer and the interface layer are formed of a monolithic device.

Claim 39 (original): The heat exchanger of claim 30, wherein the manifold layer is coupled to the interface layer.

Claim 40 (original): The heat exchanger of claim 39, wherein the manifold layer is coupled to the interface layer by adhesive bonding.

Claim 41 (original): The heat exchanger of claim 39, wherein the manifold layer is coupled to the interface layer by thermal fusing.

Claim 42 (original): The heat exchanger of claim 39, wherein the manifold layer is coupled to the interface layer by anodic bonding.

Claim 43 (original): The heat exchanger of claim 39, wherein the manifold later is coupled to the interface layer by eutectic bonding.

Claim 44 (original): The heat exchanger of claim 30, wherein the manifold layer comprises a material selected from the group consisting essentially of a plastic, a glass, a metal, and a semiconductor.

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Claim 45 (original): The heat exchanger of claim 30, wherein the manifold layer comprises a first plurality of interconnected hollow fingers and a second plurality of interconnected hollow fingers, the first plurality of interconnected hollow fingers providing flow paths to the one or more first apertures and the second plurality of interconnected hollow fingers providing flow paths from the one or more second apertures.

Claim 46 (original): The heat exchanger of claim 45, wherein the first plurality of interconnected hollow fingers and the second plurality of interconnected hollow fingers lie substantially in a single plane.

Claim 47 (original): The heat exchanger of claim 45, further comprising a pump coupled to the first plurality of interconnected hollow fingers.

Claim 48 (original): The heat exchanger of claim 30, further comprising a heat-generating source coupled to the interface layer.

Claim 49 (original): The heat exchanger of claim 48, wherein the heat-generating source comprises a semiconductor microprocessor.

Claim 50 (original): The heat exchanger of claim 48, wherein the heat-generating source is integrally formed to a bottom surface of the interface layer.

Claim 51 (original): The heat exchanger of claim 30, wherein each aperture lies substantially in a single plane, parallel to a lower surface of the interface layer.

Claim 52 (original): The heat exchanger of claim 30, wherein the manifold layer comprises a surface that extends into each trench and substantially conforms to a contour of each narrowing trench.

Claim 53 (original): The heat exchanger of claim 30, wherein a depth:width aspect ratio for at least one of the plurality of narrowing trenches is at least 10:1.

Claim 54 (original): The heat exchanger of claim 30, further comprising an intermediate layer positioned between the manifold layer and the interface layer, the intermediate layer comprising a plurality of openings positioned over the plurality of apertures, thereby controlling the flow of a cooling material to the paths.

Claim 55 (new): A method of forming a heat exchanger, comprising:

- a. forming a manifold layer defining a plurality of apertures;
- b. forming an interface layer comprising one or more narrowing trenches, each aperture positioned on one side of a narrowing trench, whereby a path is defined from a first aperture, through a narrowing trench, and to a second aperture; and
- c. coupling an intermediate layer between the manifold layer and the interface layer, the intermediate layer comprising a plurality of openings positioned over the plurality of apertures, thereby controlling the flow of a cooling material to the paths.

Claim 56 (new): A heat exchanger comprising:

- a. a manifold layer defining a plurality of apertures;
- b. an interface layer comprising a plurality of narrowing trenches, each aperture positioned on one side of a narrowing trench, whereby a path is defined from a first aperture, through a narrowing trench, and to a second aperture; and
- c. an intermediate layer positioned between the manifold layer and the interface layer, the intermediate layer comprising a plurality of openings positioned over the plurality of apertures, thereby controlling the flow of a cooling material to the paths.